

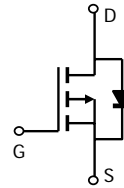
SOT-23 Plastic-Encapsulate MOSFETS

LJ3401 P-Channel Enhancement Mode Field Effect Transistor

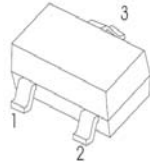
FEATURE

- High dense cell design for extremely low $R_{DS(ON)}$.
- Exceptional on-resistance and maximum DC current capability

MARKING: R1



SOT-23

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1. GATE
 2. SOURCE
 3. DRAIN

Maximum ratings ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current	I_D	-4.2	A
Power Dissipation	P_D	350	mW
Thermal Resistance from Junction to Ambient (t<5s)	$R_{\theta JA}$	357	$^{\circ}\text{C}/\text{W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55~+150	$^{\circ}\text{C}$

Electrical characteristics (T_a=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = -250μA	-30			V
Zero gate voltage drain current	I _{DSS}	V _{DS} = -24V, V _{GS} = 0V			-1	μA
Gate-source leakage current	I _{GSS}	V _{GS} = ±12V, V _{DS} = 0V			±100	nA
On characteristics						
Drain-source on-resistance (note 1)	R _{DS(on)}	V _{GS} = -10V, I _D = -4.2A			65	mΩ
		V _{GS} = -4.5V, I _D = -4A			75	mΩ
		V _{GS} = -2.5V, I _D = -1A			90	mΩ
Forward transconductance (note 1)	g _{FS}	V _{DS} = -5V, I _D = -5A	7			S
Gate threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250μA	-0.7		-1.3	V
Dynamic characteristics (note 2)						
Input capacitance	C _{iss}	V _{DS} = -15V, V _{GS} = 0V, f = 1MHz		954		pF
Output capacitance	C _{oss}			115		pF
Reverse transfer capacitance	C _{rss}			77		pF
Switching characteristics (note 2)						
Turn-on delay time	t _{d(on)}	V _{GS} = -10V, V _{DS} = -15V, R _L = 3.6Ω, R _{GEN} = 6Ω			6.3	ns
Turn-on rise time	t _r				3.2	ns
Turn-off delay time	t _{d(off)}				38.2	ns
Turn-off fall Time	t _f				12	ns
Drain-source diode characteristics and maximum ratings						
Diode forward voltage (note 1)	V _{SD}	I _S = -1A, V _{GS} = 0V			-1	V

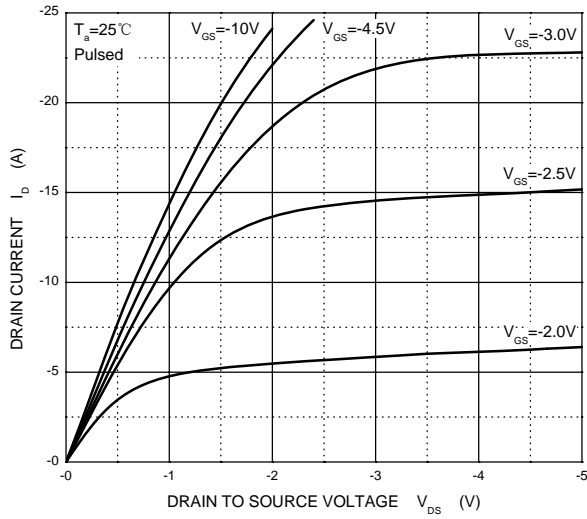
Note :

1. Pulse Test : Pulse width ≤ 300μs, duty cycles ≤ 2%.
2. These parameters have no way to verify.

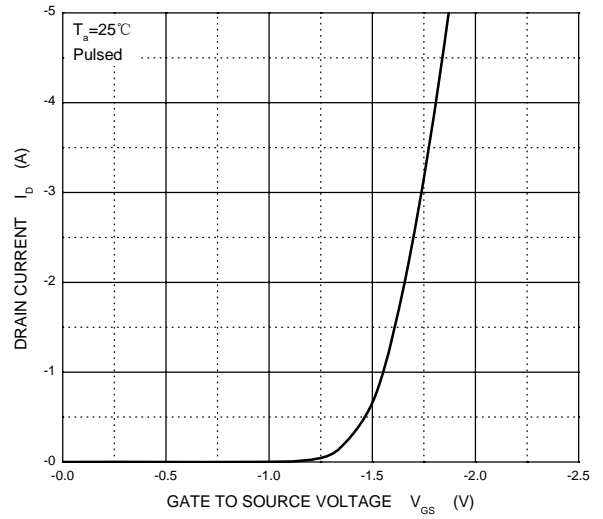
Typical Characteristics

LJ3401

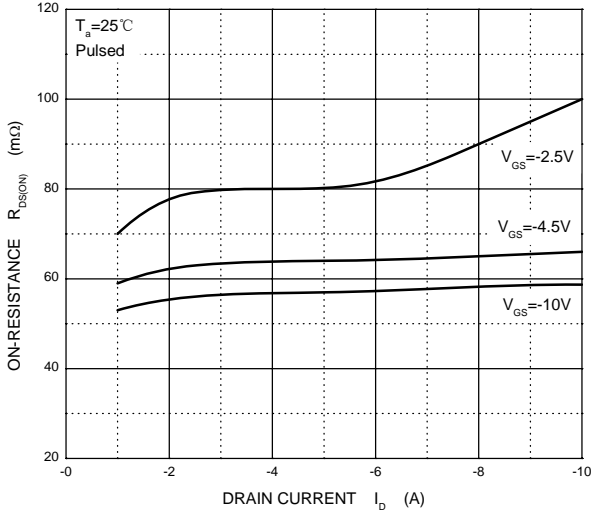
Output Characteristics



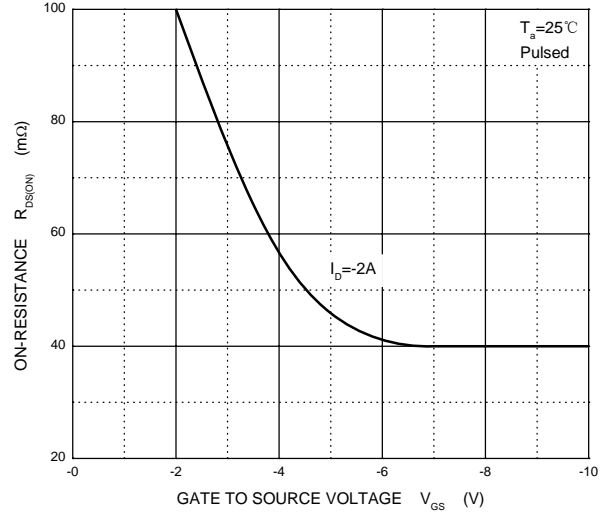
Transfer Characteristics



$R_{DS(ON)}$ — I_D



$R_{DS(ON)}$ — V_{GS}



I_S — V_{SD}

